

# Introduction

- How does MOSFET's behave in DC circuits?
- We will neglect the effects of channel length modulation (assuming  $\lambda = 0$ ).
- We will work in terms of overdrive voltage  $v_{OV}$ , which reduces need to distinguish between PMOS and NMOS.

## MOSFET circuits at DC

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## Review: Regions of Operation of a MOSFET Transistor

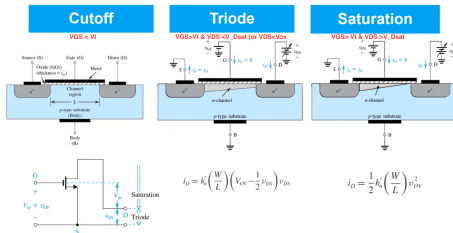
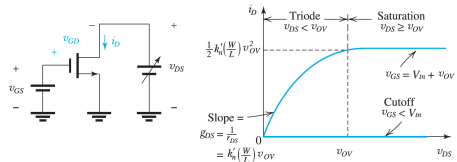


FIG 1

## Review: Regions of Operation of an NMOS Transistor

- $v_{GS} < V_T$ —no channel. The transistor is in the cut-off mode.  
 $i_D = 0$

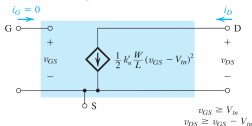


<sup>0</sup> In the triode,  $i_D$  is controlled by three terminals (hence the name triode), unlike in the saturation mode, where the transistor's operation is controlled by two terminals

# Analysis at DC

A MOSFET is non-linear, and has different operating modes:

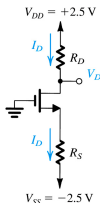
- 1 Cut-off, when  $v_{GS} < V_t$ 
  - $i_D = 0$
  - no channel is formed
- 2 Triode, when  $v_{GS} = V_t + v_{OV}$ 
  - Existence of a resistance  $r_{DS} = k_n v_{OV}$  between the drain and the source
  - This model is not accurate when as the  $v_{DS}$  get close to  $v_{OV}$
- 3 Saturation, when  $v_{DS} \geq v_{OV}$



## EXAMPLES

### Example 1

Determine the values of  $R_D$  and  $R_S$  so that the transistor operates at  $i_D = 0.4\text{mA}$  and  $V_D = +0.5\text{V}$ . The NMOS transistor has  $V_t = 0.7\text{V}$ ,  $\mu_n C_{ox} = 100\mu\text{A}/\text{V}^2$ ,  $L = 1\mu\text{m}$ , and  $W = 32\mu\text{m}$ . Neglect the channel-length modulation effect (i.e., assume that  $\lambda = 0$ ).



### Example 1—Solution

- For a  $V_D$  voltage, we have

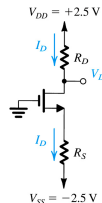
$$R_D = \frac{V_{DD} - V_D}{I_D} = \frac{2.5 - 0.5}{0.4} = 5\text{k}\Omega \quad (1)$$

- Calculating  $R_S$  is a bit more complex because we need to know the voltage at the source terminal.

- Since  $V_D = 0.5 > V_G$ , the transistor is in the **saturation mode**. Thus,

$$I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} V_{OV}^2 \quad (2)$$

The overdrive voltage is thus given by



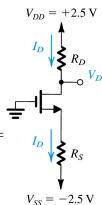
## Example 1—Solution

- It is now possible to calculate  $V_{GS}$

$$V_{GS} = V_t + V_{OV} = 0.7V + 0.5V = 1.2V \quad (4)$$

- The source resistor is thus given by

$$R_S = \frac{V_G - V_S - V_{SS}}{I_D} = \frac{0 - 1.2 - (-2.5)}{0.4} = \quad (5)$$



## Example 2

Find the value of  $R$  that results in  $V_D = 0.7V$ . The MOSFET has  $V_{tn} = 0.5V$ ,  $\mu_n C_{ox} = 0.4 \text{ mA V}^{-2}$ ,  $W = 0.72 \mu\text{m}$ ,  $L = 0.18 \mu\text{m}$  and  $\lambda = 0$

- Saturation mode since  $v_{GD} = 0 < V_{tn}$

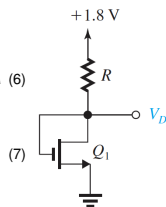
- Thus, the drain current is given by

$$i_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_D - V_{tn})^2 = 0.032 \text{ mA} \quad (6)$$

- The resistor  $R$  is given by

$$R = (1.8V - V_D) / I_D$$

- Since  $V_D = 1.8V - I_D R = 0.7V$ ,



The end